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### SD1727 (THX15) **RF POWER BIPOLAR TRANSISTORS** HF SSB APPLICATIONS

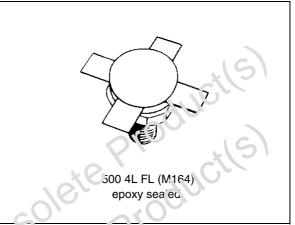
#### **FEATURES SUMMARY**

- OPTIMIZED FOR SSB
- 30 MHz
- 50 VOLTS
- IMD –30 dB
- COMMON EMITTER
- GOLD METALLIZATION
- POUT = 150 W PEP MIN. WITH 14 dB GAIN

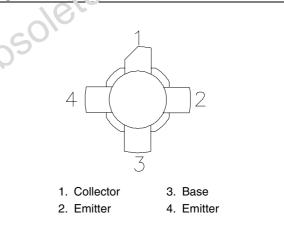
#### DESCRIPTION

The SD1727 is a 50 V epitaxial silicon NPN planar transistor designed primarily for SSB communications. This device utilizes emitter ballasting to = or = or product(s) obsolete product(s) obsolete product(s) product(s) achieve extreme ruggedness under severe oper-

#### Figure 1. Package



#### Figure 2. Pir Connection



Order Codes	Marking	Package	Packaging
SD1727 (THX15)	SD1727	M164	BLACK CARDBOARDS

#### SD1727 (THX15)

Symbol	Parameter	Value	Unit
V <sub>CBO</sub>	Collector-Base Voltage	110	V
V <sub>CEO</sub>	Collector-Emitter Voltage	55	V
V <sub>EBO</sub>	Emitter-Base Voltage	4.0	V
Ic	Device Current	10	A
P <sub>DISS</sub> Power Dissipation		233	W
TJ	Junction Temperature	+200	°C
T <sub>STG</sub>	Storage Temperature	– 65 to +150	°C

#### Table 2. Absolute Maximum Ratings (T<sub>case</sub> = 25°C)

#### Table 3. Thermal Data

Symbol	Parameter	Value	Unit
R <sub>TH(j-c)</sub>	Junction-Case Thermal Resistance	0 75	°C/W

#### ELECTRICAL SPECIFICATIONS (T<sub>case</sub> = 25°C)

#### Table 4. Static

T <sub>STG</sub>	Storage Temperature	- 65 to +150			°C
ble 3. Ther	mal Data			d	51
Symbol	Parameter	Value			Unit
R <sub>TH(j-c)</sub>	Junction-Case Thermal Resistance		0 75		°C/W
ECTRICAL ble 4. Stati	c	ste		JUCE	
Symbol	Test Conditions	Value Min. Typ. Max.		Unit	
BV <sub>CBO</sub>	I <sub>C</sub> = 100 mA; I <sub>E</sub> = 0 mA	110			v
BV <sub>CES</sub>	I <sub>C</sub> = 100 mA; V <sub>BE</sub> = 0 v	110			v
					1
BV <sub>CEO</sub>	I <sub>C</sub> = 100 mA; I <sub>5</sub> = 0 r.A	55	—	—	V
BV <sub>CEO</sub> BV <sub>EBO</sub>		55 4.0			V V
	I <sub>C</sub> = 100 mA; I <sub>5</sub> = 0 r .A			 5	
BV <sub>EBO</sub>	$I_{C} = 100 \text{ mA}; I_{5} = 0 \text{ r.A}$ $I_{E} = 10 \text{ r.A}; I_{C} = 0 \text{ mA}$			— — 5 5	V

#### Table 5. Dynamic

Symbol	Test Conditions	Value			Unit
Symbol		Min.	Тур.	Max.	onne
Роит	$f = 30 \text{ MHz}; V_{CE} = 50 \text{ V}; I_{CQ} = 100 \text{ mA}$	150		_	W
G <sub>P</sub> <sup>(1)</sup>	$P_{OUT} = 150 \text{ W PEP}; V_{CE} = 50 \text{ V}; I_{CQ} = 100 \text{ mA}$	14		_	dB
IMD <sup>(1)</sup>	$P_{OUT} = 150 \text{ W PEP}; V_{CE} = 50 \text{ V}; I_{CQ} = 100 \text{ mA}$	_		-30	dBc
ηc <sup>(1)</sup>	$P_{OUT} = 150 \text{ W PEP}; V_{CE} = 50 \text{ V}; I_{CQ} = 100 \text{ mA}$	37			%
C <sub>OB</sub>	f = 1 MHz; V <sub>CB</sub> = 50 V			220	pF

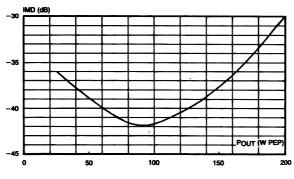
Note: The SD1727 is also usable in Class A at 40 V. Typical performance is:  $P_{OUT} = 30 \text{ W PEP}, G_P = 14 \text{ dB}, \text{IMD} = -40 \text{dBc}$ 

Note: 1. f<sub>1</sub> = 30.00 MHz; f<sub>2</sub> = 30.001 MHz



#### **TYPICAL PERFORMANCE**

Figure 3. Intermodulation Distortion vs Power Output PEP



### Figure 5. Collector Efficiency vs Power Output PEP

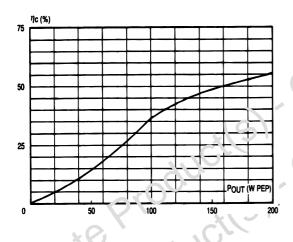
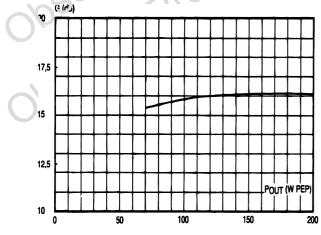
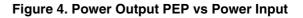


Figure 7 Power Gain vs Power Output PEP





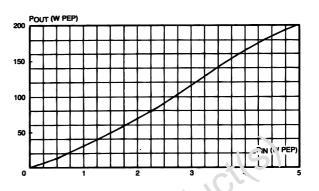
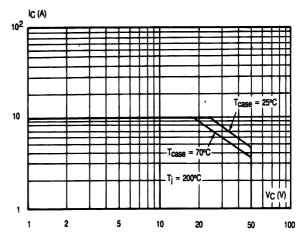


Figure 6. Power Gain is Frequency



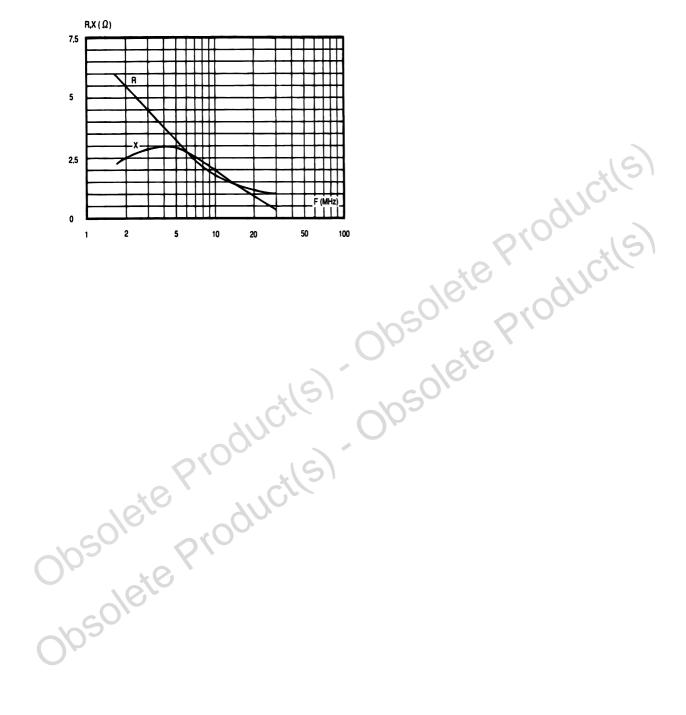
#### Figure 8. Safe Operating Area



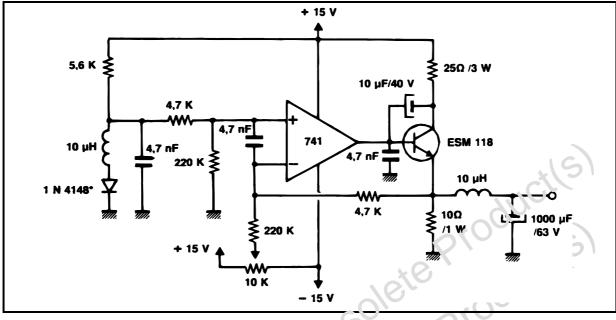
#### SD1727 (THX15)

#### **IMPEDANCE DATA**

#### Figure 9. Typical Input Impedance



#### **BIAS CIRCUIT**



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Figure 10. Bias Circuit

TEST CIRCUIT - CLASS AB – 30 MHZ

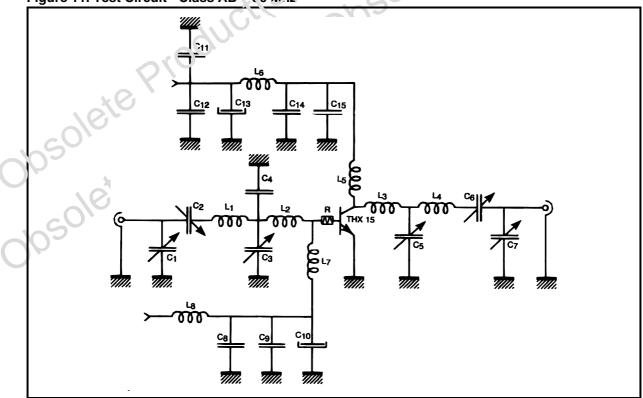


Figure 11. Test Circuit - Class AB -- . 10 M 12

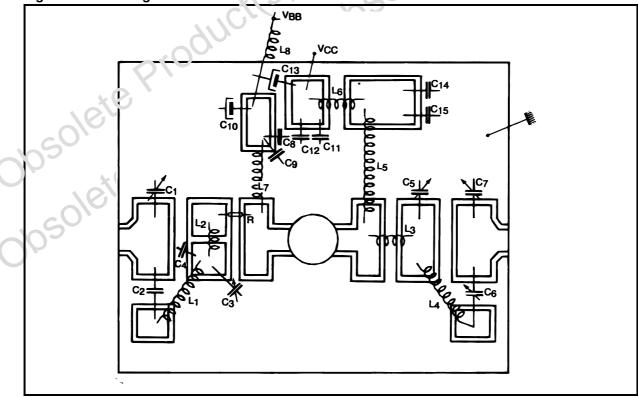
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C1	Arco 427
C2	Arco 4611
C3	Arco 4615
C4	220pF
C5, C6	Arco 4215
C7	Arco 426
C8. C12	100nF 63V
C9, C11, C15	1nF
C10	470µF 40V
C13	220µF 63V
C14	10nF
L1	5 Turns Diameter 8mm, 1.3mm Wire, Length 15mm
L2	Hair Pin Copper Foil 20 x 5mm, 0.2mm Thick
L3	1 Turn Diameter 10mm, 1.3mm Wire, Length 8mm
L4	6 Turns Diameter 8mm, 1.3mm Wire, Length 25mn.
L5	4 Turns Diameter 12mm, 2mm Wire, Length 25mm
L6, L7, L8	Choke
R	0.6Ω
MOUNTING CIRCUI	T - CLASS AB - 30 MHZ

#### Table 6. Test Circuit - Class AB – 30 Mhz

### MOUNTING CIRCUIT - CLASS AB - 30 MHZ

### Figure 12. Mounting Circuit - Class AB - 30 Mhz



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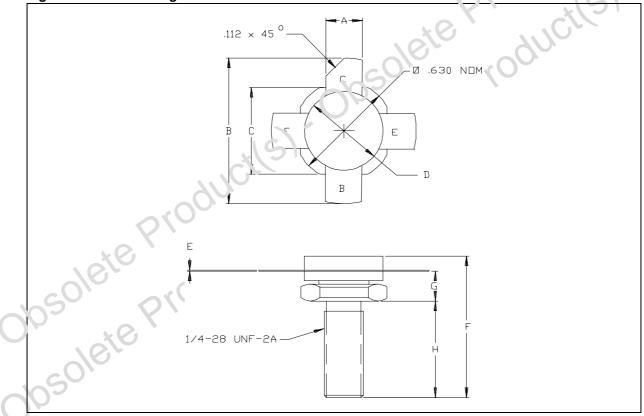
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#### PACKAGE MECHANICAL

#### Table 7. M164 Mechanical Data

Sumbol	millimeters			inches		
Symbol	Min	Тур	Max	Min	Тур	Max
А	5.59		5.84	0.220		0.230
В			26.67			1.050
С	13.84		14.10	0.545		0.555
D	12.57		12.83	0.495		0.505
Е	0.08		0.18	0.003		0.007
F			21.08			0.236
G	4.70		5.03	0.185		0. i 98
Н	12.62		13.46	0.497	11	0.530

#### Figure 13. M164 Package Dimensions



Note: Drawing is not to scale.

#### SD1727 (THX15)

#### **REVISION HISTORY**

#### **Table 8. Revision History**

Date	Revision	Description of Changes
November-1992	1	First Issue
8-June-2004	2	Stylesheet update. No content change.

Obsolete Product(s) - Obsolete Product(s) Obsolete Product(s) - Obsolete Product(s)

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